innodisk

U.2SSD

4TS2-P Series

Customer:
Customer
Part
Number:
Innodisk
Part
Number:
Innodisk
Model Name:
Date:

Innodisk	Customer		
Approver	Approver		

Total Solution For Industrial Flash Storage

Features:

- PCIe Gen.4 x 4, NVMe SSD
- Micron 3D TLC NAND
- U.2 SSD 4TS2-P
- Standard Temperature
- iPowerguard
- iDataguard
- Dynamic Thermal Management
- Hybrid Write

Performance:

- Sequential Read up to 7,100 MB/s
- Sequential Write up to 6,050 MB/s

Power Requirements:

Input Voltage:	+12 DC +- 5%
Max Operating Wattage:	10.6W
Idle Wattage:	2.5W

Reliability:

Capacity	TBW DWPC	
400GB	TBD	3
800GB	TBD	3
1.6TB	TBD	3
3.2TB	TBD	3

Data Retention	1 Year
Warranty	5 Years

DWPD based on Enterprise workload with 5 years limited warranty

For warranty details, please refer to:

https://www.innodisk.com/en/support_and_service/warrant



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REVISION HISTORY

Revision	Description	Date
V1.0	First release	May, 2023



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1. Product Overview

1.1 Introduction of Innodisk U.2 SSD 4TS2-P

Innodisk U.2 SSD 4TS2-P is an NVM Express SSD designed as PCIe SFF-8639 module with PCIe interface and 3D TLC NAND Flash. U.2 SSD 4TS2-P supports PCIe Gen IV x4, and it is compliant with NVMe 1.4 providing excellent performance. With sophisticated error detection and correction (ECC) functions, the module can ensure full End-to-end Data Path Protection that secures the data transmission between host system and NAND Flash.

Innodisk U.2 SSD 4TS2-P provides ultra-speed and high IOPS and offers maximum capacity up to 3.2TB, making the SSD optimal for server and heavy data workload applications.

CAUTION TRIM must be enabled.

TRIM enables SSD's controller to skip invalid data instead of moving. It can free up significant amount of resources, extends the lifespan of SSD by reducing erase, and write cycles on the SSD. Innodisk's handling of garbage collection along with TRIM command improves write performance on SSDs.

1.2 Product View and Models

Innodisk U.2 SSD 4TS2-P is available in follow capacities within 3D TLC flash ICs.

U.2 (P80) 4TS2-P 400GB U.2 (P80) 4TS2-P 800GB U.2 (P80) 4TS2-P 1.6TB U.2 (P80) 4TS2-P 3.2TB



Figure 1: U.2 SSD 4TS2-P

1.3 PCIe Interface

Innodisk U.2 SSD 4TS2-P supports PCIe Gen IV interface and compliant with NVMe 1.4. U.2 SSD 4TS2-P can work under PCIe Gen 1, Gen 2, Gen 3 & Gen4.

Most of operating system includes NVMe in-box driver now. For more information about the driver support in each OS, please visit http://nvmexpress.org/resources/drivers.



2. Product Specifications

2.1 Capacity and Device Parameters

U.2 SSD 4TS2-P device parameters are shown in Table 1.

Capacity	LBA	User Capacity(MB)
400GB	781422768	381554
800GB	1562824368	763097
1.6TB	3125627568	1526185
3.2TB	6251233968	3052360

Table 1: Device parameters

2.2 Performance

Burst Transfer Rate: 8 GB/s

		III Edycie			
Capacity	Unit	400GB	800GB	1.6TB	3.2TB
Sequential**	MB/s	6 950	6.000	7 100	6 000
Read (Q8T1)		0,050	0,900	7,100	0,900
Sequential**		2 500	4 750	6 050	E 200
Write (Q1T1)		2,500	4,750	0,050	5,200
Steady Sequential		2 650	2 650	2 150	1 700
Read**		2,050	2,650	2,150	1,700
Steady Sequential		000	1 700	2 100	2 150
Write**		000	1,700	2,100	2,150
4KB Random**		E48 000	021 000	1 107 000	005 000
Read (Q32T16)	IOPS	548,000	921,000	1,197,000	903,000
4KB Random**		641 000	814 000	1 042 000	917 000
Write (Q32T16)		041,000	314,000	1,043,000	317,000

Table 2: Performance - 112 Layers 3D TLC

Note*: Performance results are based on CrystalDiskMark 7.0.0 with file size 1000MB of Queue Depth 32. Note**: Performance results are based on AIDA 64 v5.98 with block size 1MB of Linear Read & Write Test



Capacity	Unit	400GB	800GB	1.6TB	3.2TB
Sequential Read	μs	44	53	63	63
Sequential Write		10	10	10	10
Random Read		61	61	62	63
Random Write		10	10	10	10

Table 3: Latency (QD1)

Note: Latency measured using 4KB(4,096 Bytes) transfer size with Queue Depth equal to 1 on a sequential and random workload

Capacity	400GB	800GB	1.6TB	3.2TB
Quality of Service ^{1,2} (99.9%) (Unit: ms)				
Read Queue Depth 1	0.07	0.07	0.08	0.08
Write Queue Depth 1	0.02	0.02	0.02	.02

Table 4: Quality of Service (QoS)

Note:

1. Quality of Service measured using 4KB (4,096 bytes) transfer size on a random workload on a full Logical Block Address (LBA) span of the drive once the workload has reached steady state but including all background activities required for normal operation and data reliability.

2. Based on Random 4KB QD=1 workloads, measured as the time taken for 99.9 percentile of commands to finish the round-trip from host to drive and back to host.

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 5: Innodisk U.2 SSD 4TS2-P Power Requirement

Item	Symbol	Rating	Unit
Input voltage	VIN	+12 DC +- 5%	V

2.3.2 Power Consumption

Table 6: Power Consumption

Mode	Power Consumption (W)
Read	7.9
Write	10.6
Idle	2.5
Power-on peak	10.8

* Target: U.2 SSD 4TS2-P 3.2TB

Note: Current results may vary depending on system components and power circuit design. Please refer to the test

report for other capacities

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 7: Temperature range for U.2 SSD 4TS2-P

Temperature	Range
Operating	Standard Grade: 0°C to +70°C
Storage	-40°C ~ +85°C

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 8: Shock/Vibration Testing for U.2 SSD 4TS2-P

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 60068-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 60068-2-27



2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various U.2 SSD 4TS2-P configurations. The analysis was performed using a RAM Commander[™] failure rate prediction.

- **Failure Rate**: The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF)**: A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 9:	U.2 SSD 4TS2-P MTBF	
	Condition	MTDE /L

Product	Condition	MTBF (Hours)
Innodisk U.2 SSD 4TS2-P	Telcordia SR-332 GB, 25°C	>3,000,000

2.5 CE and FCC Compatibility

U.2 SSD 4TS2-P conforms to CE and FCC requirements.

2.6 RoHS Compliance

U.2 SSD 4TS2-P is fully compliant with RoHS directive.

2.7 Reliability

Parameter	Value	
Flash endurance	10,000 P/E cycles	
Error Correct Code	Support (LDPC)	
Data Retention	Under 40°C:	
	10 Yeas at initial NAND Status.	
TBW* (Total Bytes Written) Unit: TB		
Capacity	Enterprise workload	
400GB	TBD	
800GB	TBD	
1.6TB	TBD	
3.2TB	TBD	

Table 10: U.2 SSD 4TS2-P TBW

* Note:

1. Based on out-of-box performance.

2. Current TBW Values are for reference only. Actual figures will be released after MP.



2.8 Transfer Mode

U.2 SSD 4TS2-P support following transfer mode: PCIe Gen IV 8GB/s PCIe Gen III 4 GB/s PCIe Gen II 2 GB/s PCIe Gen I 1 GB/s

2.9 Pin Assignment

Innodisk U.2 SSD 4TS2-P follows standard SFF-8639 spec as below. Mechanical details are documented in SFF-8639: Multifunction 6X Unshielded Connector.

Pin	Mate	Name
P1	3rd	WAKE#
P2	3rd	-
P3	2nd	PWRDIS
P4	1st	IfDet#
Р5	2nd	Ground
P6	2nd	Ground
P7	2nd	-
P8	3rd	-
P9	3rd	-
P10	2nd	-
P11	3rd	ACTIVITY#
P12	1st	Ground
P13	2nd	+12V Precharge
P14	3rd	+12V
P15	3rd	+12V
S1	2nd	Ground
S2	3rd	-
S3	3rd	-
S4	2nd	Ground
S5	3rd	-
S6	3rd	-
S7	2nd	Ground
S8	2nd	Ground
S9	3rd	-
S10	3rd	-
S11	2nd	Ground
S12	3rd	-
S13	3rd	-
S14	2nd	Ground
S15	3rd	-
S16	2nd	Ground
S17	3rd	PETp1

Table 11: Innodisk U.2 SSD 4TS2-P Pin Assignment

Pin	Mate	Name
S18	3rd	PETn1
S19	2nd	Ground
S20	3rd	PERn1
S21	3rd	PERp1
S22	2nd	Ground
S23	3rd	PETp2
S24	3rd	PETn2
S25	2nd	Ground
S26	3rd	PERn2
S27	3rd	PERp2
S28	2nd	Ground
E1	3rd	-
E2	3rd	-
E3	3rd	-
E4	3rd	-
E5	3rd	PERST#
E6	3rd	-
E7	3rd	RefClk0+
E8	3rd	RefClk0-
E9	2nd	Ground
E10	3rd	PETp0
E11	3rd	PETn0
E12	2nd	Ground
E13	3rd	PERn0
E14	3rd	PERp0
E15	2nd	Ground
E16	3rd	-
E17	3rd	РЕТр3
E18	3rd	PETn3
E19	2nd	Ground
E20	3rd	PERn3
E21	3rd	PERp3
E22	2nd	Ground
E23	3rd	-
E24	3rd	-
E25	3rd	-



Table 12: Innodisk U.2 SSD 4TS2-P LED indicator

LED Colo	r Function
Chaon	Power on
Green	Access

2.10 Mechanical Dimensions



Figure 2: U.2 SSD 4TS2-P Mechanical Dimensions

2.11 Assembly Weight

An Innodisk U.2 SSD 4TS2-P within NAND flash ICs, 400GB's weight is 14 grams approximately.

2.12 Seek Time

Innodisk U.2 SSD 4TS2-P is not a magnetic rotating design. There is no seek or rotational latency required.

2.13 NAND Flash Memory

Innodisk U.2 SSD 4TS2-P uses 3D TLC NAND flash memory, which is non-volatility, high reliability and high speed memory storage.



3. Theory of Operation

3.1 Overview

Figure 2 shows the operation of Innodisk U.2 SSD 4TS2-P from the system level, including the major hardware blocks.



Figure 3: Innodisk U.2 SSD 4TS2-P Block Diagram

Innodisk U.2 SSD 4TS2-P integrates a PCIe Gen IV x4 controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard NVM protocol. Communication with the flash device(s) occurs through the flash interface.

3.2 PCIe Gen IV x4 Controller

Innodisk U.2 SSD 4TS2-P is a PCIe Gen IVx4 controller is compliant with NVMe 1.4, up to 32.0Gbps transfer speed. Also it is compliant with PCIe Gen 1, Gen 2, Gen 3 and Gen 4 specification. The controller supports up to 8 channels for flash interface.



3.3 Error Detection and Correction

Innodisk U.2 SSD 4TS2-P is designed with hardware LDPC ECC engine with hard-decision and soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.

3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk U.2 SSD 4TS2-P uses a combination of two types of wear leveling- dynamic and static wear leveling- to distribute write cycling across an SSD and balance erase count of each block, thereby extending flash lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 iData Guard

Innodisk's iData Guard is a comprehensive data protection mechanism that functions before and after a sudden power outage to the SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's iData Guard provides effective power cycling management, preventing data stored in flash from degrading with use.

3.7 Garbage Collection/TRIM

Garbage collection and TRIM technology is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.



3.8 Thermal Management

U.2 SSD 4TS2-P has built-in thermal sensor which can detect environment temperature of SSD. In the meantime, firmware will monitor the thermal sensor to prevent any failure of overheating. During extreme temperature, firmware will adjust the data transfer behavior to maintain the SSD's reliable operation.

3.9 iPower Guard

iPower Guard technology is a set of preventive measures that protect the SSD in an unstable power supply environment. This comprehensive package comprises safeguards for startup and shutdown to maintain device performance and ensure data integrity.

3.10 Die RAID

Die RAID is a controller function which leveraged user capacity to back up the data in NAND flash. Die RAID supported can ensure the user data in the NAND Flash more consistent in certain scenario. Innodisk U.2 SSD 4TS2-P series is default enable the Die RAID function for the industrial application.

3.11 SLC Cache

4TS2-P series adopt hybrid mode which enables SLC Cache up to 3% of total user capacity followed by TLC direct write to strike balance between burst performance and steady overall stability. The SLC Cache buffer size are defined as table below.

Capacity	400GB	800GB	1.6TB	3.2TB		
SLC cache (GB)	12	24	49.1	98.3		
SLC cache (%)	3	3	3	3		

Table 13: U.2 SSD 4TS2-P SLC cache



4. Installation Requirements

4.1 U.2 SSD 4TS2-P Pin Directions



Figure 4: Device Signal Segment Power Segment



Figure 5: Signal Segment and Power Segment(Host/cable side)

4.2 Electrical Connections for U.2 SSD 4TS2-P

U.2 SSD 4TS2-P follows standard SFF-8639 spec, Mechanical details are documented in SFF-8639: Multifunction 6X Unshielded Connector, it is a total of 68 contacts, not all contacts may be utilized. U.2 SSD 4TS2-P only support PCIe interface, see more details in *2.9 Pin Assignment.*

4.3 Device Drive

U.2 SSD 4TS2-P is compliant with NVMe 1.4. Both Operation System and BIOS should include NVMe driver to compatible with NVMe device. Nowadays, most of OS includes NVMe in-box driver now. For more information about the driver support in each OS, please visit the website <u>http://nvmexpress.org/resources/drivers</u>. For BIOS NVMe driver support please contact with motherboard manufacturers.



5. SMART / Health Information

This log page is used to provide SMART and general health information. The information provided is over the life of the controller and is retained across power cycles. More details about Set Features command; please refer to NVM Express 1.3

5.1 Get Log Page(Log Identifier 02h)

Innodisk 4TS2-P series SMART / Health Information Log are listed in following table.

Bytes	Description												
0	Critical Warning: This field indicates critical warnings for the state of the controller. Each bit												
	corresponds to a critical warning type; multiple bits may be set. If a bit is cleared to '0', th warning does not apply. Critical warnings may result in an asynchronous event notification												
	Bits in this field represent the current associated state and are not persistent.												
	Bit Definition												
	00	If set to '1', then the available spare space has fallen below the											
		threshold.											
	01	If set to '1', then a temperature is above an over temperature threshold											
		or below an under											
	02	If set to '1', then the NVM subsystem reliability has been degraded due											
		to significant media related											
	03	If set to '1', then the media has been placed in read only mode.											
	04	If set to '1', then the volatile memory backup device has failed. This field											
		is only valid if the											
	07:05	Reserved											
2:1	Composite Temperature: Contains a value corresponding to a temperature in degrees Kelvin that												
	represents the	e current composite temperature of the controller and namespace(s) associated with that											
	controller. The manner in which this value is computed is implementation specific and may represent the actual temperature of any physical point in the NVM subsystem. The value of this f												
	may be used	to trigger an asynchronous event.											
	Warning and	critical overheating composite temperature threshold values are reported by the											
	d CCTEMP fields in the Identify Controller data structure.												
3	Available Sp	are: Contains a normalized percentage (0 to 100%) of the remaining spare capacity											
	available.												

Table 14: Get Log Page – SMART / Health Information Log

innodisk	U.2 SSD 4TS2-P
4	Available Spare Threshold: When the Available Spare falls below the threshold indicated in this field,
	an asynchronous event completion may occur. The value is indicated as a normalized percentage (0
	to 100%).
5	Percentage Used: Contains a vendor specific estimate of the percentage of NVM subsystem life used
	based on the actual usage and the manufacturer's prediction of NVM life. A value of 100 indicates that
	the estimated endurance of the NVM in the NVM subsystem has been consumed, but may not indicate
	an NVM subsystem failure. The value is allowed to exceed 100. Percentages greater than 254 shall be
	represented as 255. This value shall be updated once per power-on hour (when the controller is not in
	a sleep state).
	Refer to the JEDEC JESD218A standard for SSD device life and endurance measurement techniques.
31:6	Reserved
47:32	Data Units Read: Contains the number of 512 byte data units the host has read from the controller;
	this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds
	to 1000 units of 512 bytes read) and is rounded up. When the LBA size is a value other than 512 bytes,
	the controller shall convert the amount of data read to 512 byte units.
	For the NVM command set, logical blocks read as part of Compare and Read operations shall be
	included in this value.
63:48	Data Units Written: Contains the number of 512 byte data units the host has written to the controller;
	this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds
	to 1000 units of 512 bytes written) and is rounded up. When the LBA size is a value other than 512
	bytes, the controller shall convert the amount of data written to 512 byte units.
	For the NVM command set, logical blocks written as part of Write operations shall be included in this
	value. Write Uncorrectable commands shall not impact this value.
79:64	Host Read Commands: Contains the number of read commands completed by the controller.
	For the NVM command set, this is the number of Compare and Read commands.
95:80	Host Write Commands: Contains the number of write commands completed by the controller.
	For the NVM command set, this is the number of Write commands.
111:96	Controller Busy Time: Contains the amount of time the controller is busy with I/O commands. The
	controller is busy when there is a command outstanding to an I/O Queue (specifically, a command was
	issued via an I/O Submission Queue Tail doorbell write and the corresponding completion queue entry
	has not been posted yet to the associated I/O Completion Queue). This value is reported in minutes.
127:112	Power Cycles: Contains the number of power cycles.
143:128	Power On Hours: Contains the number of power-on hours. This may not include time that the controller
	was powered and in a non-operational power state.
159:144	Unsafe Shutdowns: Contains the number of unsafe shutdowns. This count is incremented when a
	shutdown notification (CC.SHN) is not received prior to loss of power.
175:160	Media and Data Integrity Errors: Contains the number of occurrences where the controller detected
	an unrecovered data integrity error. Errors such as uncorrectable ECC, CRC checksum failure, or LBA
	tag mismatch are included in this field.

innodisk	U.2 SSD 4TS2-P
191:176	Number of Error Information Log Entries: Contains the number of Error Information log entries over
	the life of the controller.
195:192	Warning Composite Temperature Time: Contains the amount of time in minutes that the controller
	is operational and the Composite Temperature is greater than or equal to the Warning Composite
	Temperature Threshold (WCTEMP) field and less than the Critical Composite Temperature Threshold
	(CCTEMP) field in the Identify Controller data structure.
	If the value of the WCTEMP or CCTEMP field is 0h, then this field is always cleared to 0h regardless
	of the Composite Temperature value.
199:196	Critical Composite Temperature Time: Contains the amount of time in minutes that the controller is
	operational and the Composite Temperature is greater than the Critical Composite Temperature
	Threshold (CCTEMP) field in the Identify Controller data structure.
	If the value of the CCTEMP field is 0h, then this field is always cleared to 0h regardless of the Composite
	Temperature value.
201:200	Temperature Sensor 1: Controller's Tj temperature
203:202	Temperature Sensor 2: Flash package's Tj temperature (Channel #0 CE #0). This Flash
	package is located the closet to the controller IC on M.2 family.
205:204	Temperature Sensor 3: Flash package's Tj temperature (Channel #0 CE #0).
	This Flash package is located the closet to the controller IC on M.2 family.
207:206	Temperature Sensor 4: Flash package's Tj temperature (Channel #7 CE #0).
209:208	Temperature Sensor 5: Flash Tj max temperature from Channel #0 to Channel #3 Flash
	packages.
211:210	Temperature Sensor 6: Flash Tj max temperature from Channel #4 to Channel #7 Flash
	packages.
213:212	Temperature Sensor 7: Flash Tj minimum temperature from Channel #0 to Channel #3
	Flash packages.
215:214	Temperature Sensor 8: Flash Tj minimum temperature from Channel #4 to Channel #7
	Flash packages.
	Thermal Management Temperature 1 Transition Count: Contains the number of times the controller
	transitioned to lower power active power states or performed vendor specific thermal management
	actions while minimizing the impact on performance in order to attempt to reduce the Composite
219:216	Temperature because of the host controlled thermal management feature (refer to section 8.4.5) (i.e.,
	the Composite Temperature rose above the Thermal Management Temperature 1.) This counter shall
	not wrap once it reaches its maximum value. A value of zero, indicates that this transition has never
	occurred or this field is not implemented.
	Thermal Management Temperature 2 Transition Count: Contains the number of times the controller
	transitioned to lower power active power states or performed vendor specific thermal management
223:220	actions regardless of the impact on performance (e.g., heavy throttling) in order to attempt to reduce
	the Composite Temperature because of the host controlled thermal management feature (refer to
	section 8.4.5) (i.e., the Composite Temperature rose above the Thermal Management Temperature 2.)

innodisk	U.2 SSD 4TS2-P									
	This counter shall not wrap once it reaches its maximum value. A value of zero, indicates that this									
	transition has never occurred or this field is not implemented.									
	Total Time For Thermal Management Temperature 1: Contains the number of seconds that the									
	controller had transitioned to lower power active power states or performed vendor specific thermal									
222.224	management actions while minimizing the impact on performance in order to attempt to reduce the									
227.224	Composite Temperature because of the host controlled thermal management feature (refer to section									
	8.4.5). This counter shall not wrap once it reaches its maximum value. A value of zero, indicates that									
	this transition has never occurred or this field is not implemented.									
	Total Time For Thermal Management Temperature 2: Contains the number of seconds that the									
	controller had transitioned to lower power active power states or performed vendor specific thermal									
221.229	management actions regardless of the impact on performance (e.g., heavy throttling) in order to attempt									
231.220	to reduce the Composite Temperature because of the host controlled thermal management feature									
	(refer to section 8.4.5). This counter shall not wrap once it reaches its maximum value. A value of zero,									
	indicates that this transition has never occurred or this field is not implemented.									
511:232	Reserved									

The innodisk U.2 SSD 4TS2-P series thermal sensor take ambient air temperature as a reference with any airflow condition, and the data can refer to iSMART.

Notes: More detailed health info has been defined by innodisk and will be shown on iSMART V5.3.21 (or later version).

6. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21
CODE	D	s	E	U	2	-	4	8	0	D	Р	1	L	С	A	Е	н	-	x	x	x
Definition																					
Code 1 st (Disk)										Code 14 th (Operation Temperature)											
D : Disk										C: Standard Grade (0° $^\circ$ C ~ +70° $^\circ$ C)											
		Co	de 2	2 nd (Feat	ure	set)						Co	de :	L5 th	(Int	erna	al co	ntro	I)	
G : Ever	Green	Serie	s									4~Z: B	GA PO	CB ver	sion.						
	(Code	e 3 rd	~5 th	י (Fo	orm f	facto	or)				Code 16 th (Channel of data transfer)									
EU2: U.2	2 SSD										(Q: Quad Channels									
												E: Eight Channels									
		Co	de 7	th ~9	9 th (0	Сара	city)				Code 17 th (Flash Type)									
400: 400)GB		800): 800	OGB		1T6:	1.6TB				H: Micron 3D TLC									
3T2: 3.2	ТВ																				
	C	Code	10 ^{ti}	"~ 1	2 th (Con	troll	er)					Coo	de 1	8 th (Opti	ona	l Fur	nctio	n)	
DP1: PC	DP1: PCle 4TS2-P																				
		6 -		ath (— 1 — –									1 Oth		act /	O				•
Code 13" (Flash mode)								C	oae	19"	~ 2	Тз. (Cus	τομι	ze c	oae)				
L: 3D IL																					